

Features

- Low Insertion Loss, 0.6 dB Typical @ 1.0 GHz
- Fast Switching Speed, 10 ns Typical
- Ultra Low DC Power Consumption
- Integral Static Protection
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- RoHS* Compliant

Description

The MASW6020G is a GaAs MMIC SPST switch die. This die is ideally used where low power consumption is required.

Typical applications include transmit / receive switching, switch matrices and switched filter banks, WLAN IEEE 802.11a and 802.11 b/g systems. Other applications include cordless phones and base stations.

Ordering Information

Part Number	Package
MASW6020G	DIE ¹

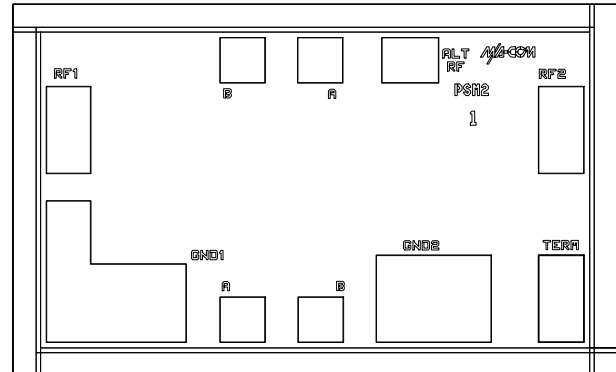
1. Die quantity varies.

Absolute Maximum Rating ^{2,3}

Parameter	Absolute Maximum
Control Value (A/B)	-8.5 VDC
Max Input RF Power	+34 dBm (500 MHz - 4 GHz)
Storage Temperature	-65°C to +175°C
Operating Temperature	+175°C

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

Pad Layout



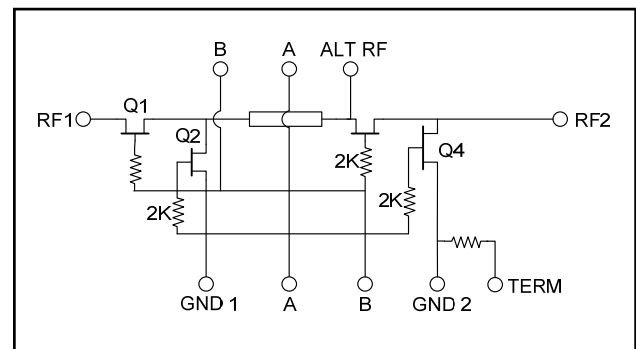
Die Size - Inches (mm)

0.05 x 0.03 x 0.004 (1.270 x 0.770 x 0.250)

Bond Pad Dimensions

Bond Pad	Dimensions - Inches (mm)
RF1, RF2	0.004 x 0.008 (0.100 x 0.200)
Alt RF	0.004 x 0.005 (0.100 x 0.125)
A, B	0.004 x 0.004 (0.100 x 0.100)
GND1	0.012 x 0.007 (0.300 x 0.175)
GND2	0.009 x 0.008 (0.225 x 0.200)
Term	0.004 x 0.008 (0.100 x 0.200)

Schematic



*Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.
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Electrical Specifications: 0 / -5 V

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Insertion Loss	DC - 1.0 GHz L/T/H	dB	—	0.8 / 1.0 / 0.9	—
	DC - 2.0 GHz L/T/H		—	0.9 / 1.1 / 1.0	—
	DC - 6.0 GHz L/T/H		—	2.5 / 2.7 / 2.5	—
Isolation	DC - 1.0 GHz L/T/H	dB	—	30 / 63 / 64	—
	DC - 2.0 GHz L/T/H		—	22 / 46 / 52	—
	DC - 6.0 GHz L/T/H		—	11 / 14 / 19	—
VSWR	DC - 1.0 GHz L/T/H	Ratio	—	1.1:1 / 1.1:1 / 1.1:1	—
	DC - 2.0 GHz L/T/H		—	1.3:1 / 1.2:1 / 1.1:1	—
	DC - 6.0 GHz L/T/H		—	2.0:1 / 2.7:1 / 2.0:1	—
Input P1dB	Above 500 MHz - 0/-5V / 0/-8V 100 MHz - 0/-5V / 0/-8V	dBm	— —	+27 / +33 +21 / +26	— —
IP2	Two Tone Input Power up to +5 dBm Above 500 MHz 100 MHz	dBm	—	+68	—
			—	+62	—
IP3	Two Tone Input Power up to +5 dBm Above 500 MHz 100 MHz	dBm	—	+46	—
			—	+40	—
Control Current	V _{IN} Low (0 to -0.2 V) V _{OUT} High (-5 V @ 50 μA Typ to -8 V)	μA	— —	— —	20 300
T-rise, T-fall	10% to 90% RF and 90% to 10% RF	ns	—	10	—
T _{ON} , T _{OFF}	50% control to 90% RF, and 50% control to 10% RF	ns	—	10	—
Transients	(In Band)	mV	—	10	—

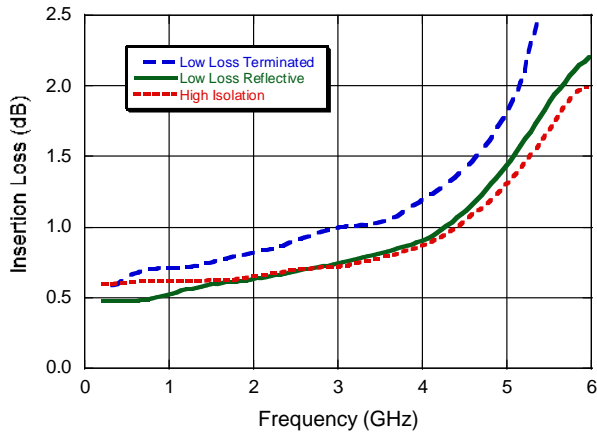
Truth Table ^{4,5}

Option	Control Voltage		Switch Condition & Bonding			Ground Bonds		
	A	B	RF1	RF2	ALT	GND1	GND2	Term
T	1	0	on	on		G		G
	0	1	off	off		G		G
L	1	0		on	on	G	G	
	0	1		off	off	G	G	
H	1	0	on	on		G	G	
	0	1	off	off		G	G	

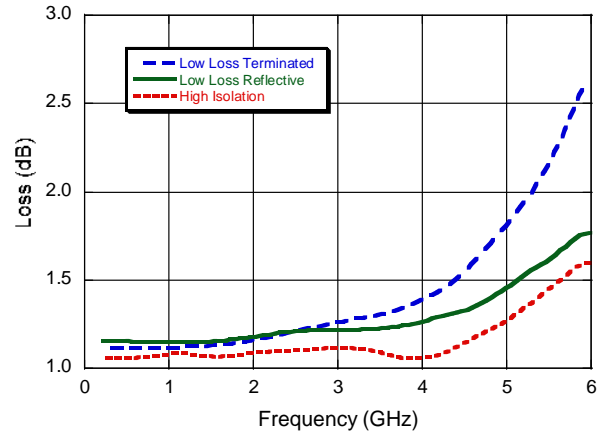
- Differential voltage, V (state 1) -V (state 2), must be 2.5 V minimum.
- 0 = 0 to -0.2 V, 1 = -5 V @ 10 μA typical to -8 V.

Typical Performance

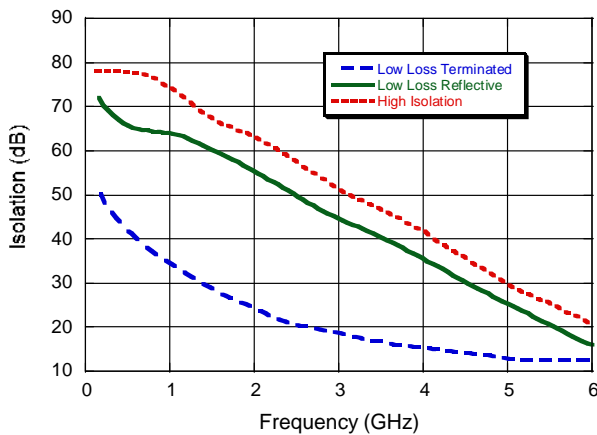
Insertion Loss



VSWR



Isolation



Handling Precautions

Permanent damage to the MASW6020G may occur if the following precautions are not adhered to:

- A. Cleanliness—MASW6020G should be handled in a clean environment. DO NOT attempt to clean unit after the MASW6020G is installed.
- B. Static Sensitivity—All chip handling equipment and personnel should be DC grounded.
- C. Transient—Avoid instrument and power supply transients while bias is applied to the MASW6020G. Use shielded signal and bias cables to minimize inductive pick-up.
- D. Bias—Apply voltage to either of the complementary control ports only when the other is grounded. No port should be allowed to “float”.
- E. General Handling—It is recommended that the MASW6020G chip be handled along the long side of the die with a sharp pair of bent tweezers. DO NOT touch the surface of the chip with fingers or tweezers.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Mounting

The MASW6020G is back-metallized with Pd/Ni/Au (100/1,000, 10,000 Å) metallization. It can be die-mounted with AuSn eutectic preforms or with thermally conductive epoxy. The package surface should be clean and flat before attachment.

Eutectic Die Attach:

- A. A 80/20 gold/tin preform is recommended with a work surface temperature of approximately 255°C and a tool temperature of 265°C. When not 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be approximately 290°C.
- B. DO NOT expose the MASW6020G to a temperature greater than 320°C for more than 20 seconds. No more than 3 seconds for scrubbing should be required for attachment.

Epoxy Die Attach:

- A. Apply a minimum amount of epoxy and place the MASW6020G into position. A thin epoxy fillet should be visible around the perimeter of the chip.
- B. Cure epoxy per manufacturer's recommended schedule.
- C. Electrically conductive epoxy may be used by is not required.

Wire Bonding

- A. Ball or wedge with 1.0 mil diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150°C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Ultrasonic energy and time should be adjusted to the minimum levels achieve reliable wirebonds.
- B. Wirebonds should be started on the chip and terminated on the package.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9